

TRANSISTOR MODULE

QCA75AA100

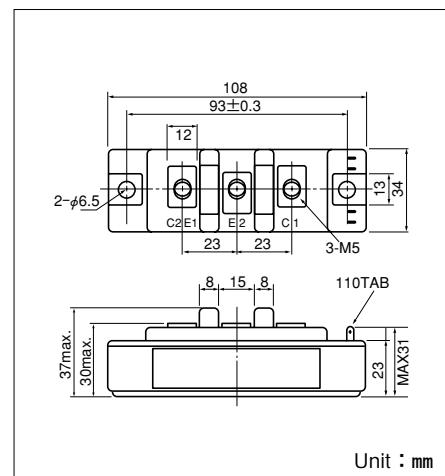
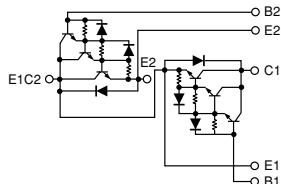
UL:E76102(M)

QCA75AA100 is a dual Darlington power transistor module which has series-connected high speed, high power Darlington transistors. Each transistor has a reverse paralleled fast recovery diode. The mounting base of the module is electrically isolated from semiconductor elements for simple heatsink construction,

- $I_C = 75A$, $V_{CEX} = 1000V$
- Low saturation voltage for higher efficiency.
- High DC current gain h_{FE}
- Isolated mounting base

(Applications)

Motor Control (VVVF), AC/DC Servo, UPS,
Switching Power Supply, Ultrasonic Application



($T_j = 25^\circ\text{C}$ unless otherwise specified)

■ Maximum Ratings

Symbol	Item	Conditions	Ratings	Unit
			QCA75AA100	
V_{CBO}	Collector-Base Voltage		1000	V
V_{CEX}	Collector-Emitter Voltage	$V_{BE} = -2V$	1000	V
V_{EBO}	Emitter-Base Voltage		7	V
I_C	Collector Current		75	A
$-I_C$	Reverse Collector Current		75	A
I_B	Base Current		4	A
P_T	Total power dissipation	$T_C = 25^\circ\text{C}$	500	W
T_j	Junction Temperature		-40 to +150	$^\circ\text{C}$
T_{stg}	Storage Temperature		-40 to +125	$^\circ\text{C}$
V_{iso}	Isolation Voltage	A.C.1minute	2500	V
M_t	Mounting Torque	Mounting (M6)	Recommended Value 2.5-3.9 (25-40)	$\text{N}\cdot\text{m}$ $\text{kgf}\cdot\text{cm}$
		Terminal (M5)	Recommended Value 1.5-2.5 (15-25)	
	Mass	Typical Value	250	g

■ Electrical Characteristics

Symbol	Item	Conditions	Ratings		Unit
			Min.	Max.	
I_{CBO}	Collector Cut-off Current	$V_{CB} = 1000V$		1.0	mA
I_{EBO}	Emitter Cut-off Current	$V_{EB} = 7V$		200	mA
$V_{CEX(SUS)}$	Collector Emitter Sustaining Voltage	$I_C = 15A$, $I_B = -4A$	1000		V
h_{FE}	DC Current Gain	$I_C = 75A$, $V_{CE} = 2.8V$	75		μs
		$I_C = 75A$, $V_{CE} = 5V$	100		
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 75A$, $I_B = 1.5A$		2.5	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C = 75A$, $I_B = 1.5A$		3.5	V
t_{on}	Switching Time	On Time		2.5	μs
t_s		Storage Time	$V_{CC} = 600V$, $I_C = 75A$ $I_B1 = 1.5A$, $I_B2 = -1.5A$	15.0	
t_f		Fall Time		3.0	
V_{ECO}	Collector-Emitter Reverse Voltage	$-I_C = 75A$		1.8	V
$R_{th(j-c)}$	Thermal Impedance (junction to case)	Transistor part		0.25	$^\circ\text{C}/\text{W}$
		Diode part		1.20	

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